Electronic Supplementary Information (ESI) for

Cost-Effective and Morphology-Controllable Niobium Diselenides for Highly Efficient Counter Electrode of Dye-Sensitized Solar Cells

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CE	V _{OC} /V	J _{SC} / (mAcm ⁻²)	FF	PCE/%	PCE of Pt /%	Compare to Pt	Reference	
MoS ₂	0.76	13.84	0.73	7.59		99.3%	1	
WS ₂	0.78	14.13	0.70	7.73	7.64	101.2%	1	
CoS	0.71	16.31	0.66	7.67	7.70	99.6%	2	
MoS ₂ /RGO	0.73	12.51	0.66	6.04	6.38	94.7%	3	
FeS ₂	0.71	15.14	0.68	7.31	7.52	97.2%	4	
Co _{0.85} Se	0.738	16.98	0.75	9.40	0.64	108.8%	_	
Ni _{0.85} Se	0.739	15.63	0.72	8.32	8.64	96.3%	5	
NbSe ₂ /C	0.77	15.58	0.65	7.80	7.90	98.7%	Our result	

Table S1 Comparison of DSC performance parameters in different documents

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CE	R_1^a/Ω	R_2^{b}/Ω	W_{1-R}^{c}	W_{1-T}	W _{1-P}	CPE_{1-T}^{d}	CPE _{1-P}
NbSe ₂ -NSs	27.72	5.18	2.52	0.054	0.392	1.281×10 ⁻⁵	0.76
NbSe ₂ -NRs	24.07	7.04	1.78	0.077	0.547	2.096×10 ⁻⁴	0.69
NbSe ₂ /C	19.38	12.41	6.63	0.080	0.479	4.78×10 ⁻⁵	0.75
Pt	8.15	4.70	4.20	0.038	0.348	7.13×10 ⁻⁵	0.76

Table S2 Detailed fitting parameters of the Nyquist plot in EIS experiments

a: R_s ; b: R_{ct} ; c: Z_N ; d: CPE.